

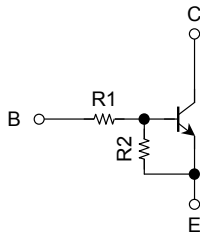
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN2967FS, RN2968FS, RN2969FS

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- Two devices are incorporated into a fine pitch Small Mold (6 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count.
Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.
- Complementary to RN1967FS~RN1969FS

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2967FS	10	47
RN2968FS	22	47
RN2969FS	47	22

Unit: mm

1.EMIITTER1	(E1)
2.EMITTER2	(E2)
3.BASE2	(B2)
4.COLLECTOR2	(C2)
5.BASE1	(B1)
6.COLLECTOR1	(C1)

fs6

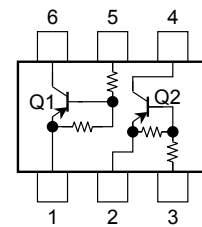
JEDEC	—
JEITA	—
TOSHIBA	2-1F1C

Weight: 0.001g (typ.)

Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Rating	Unit
Collector-base voltage	RN2967FS~RN2969FS	V _{CB0}	-20	V
Collector-emitter voltage		V _{CE0}	-20	V
Emitter-base voltage	RN2967FS	V _{EBO}	-6	V
	RN2968FS		-7	
	RN2969FS		-15	
Collector current	RN2967FS~RN2969FS	I _C	-50	mA
Collector power dissipation		P _C	50	mW
Junction temperature		T _j	150	°C
Storage temperature range		T _{stg}	-55~150	°C

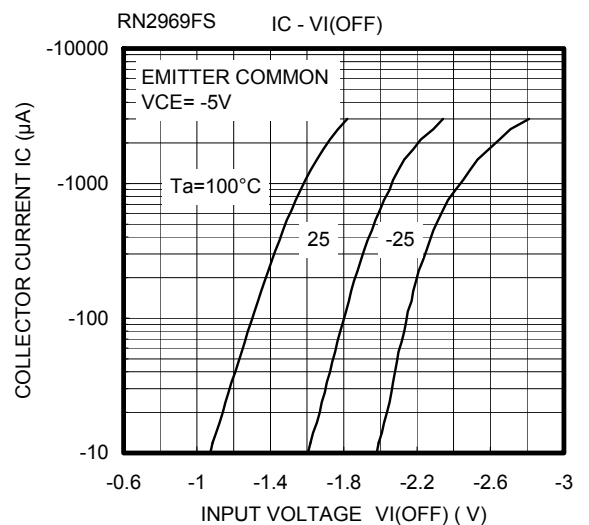
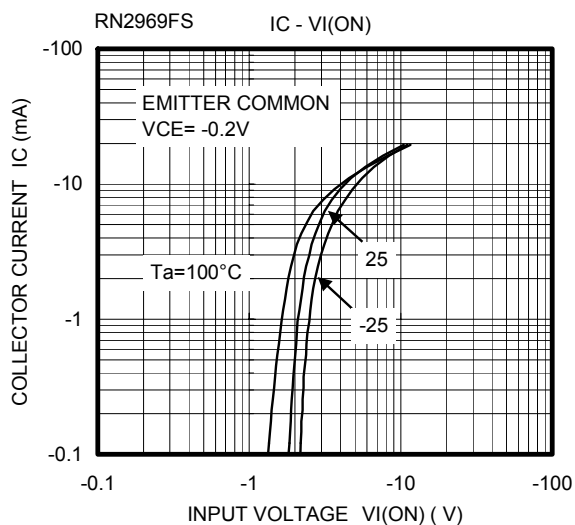
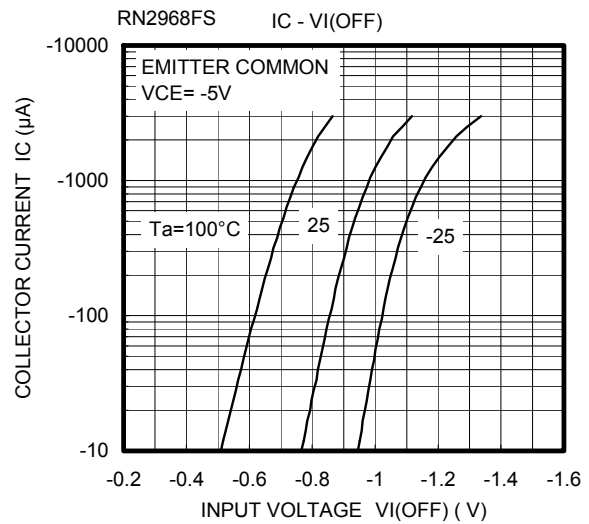
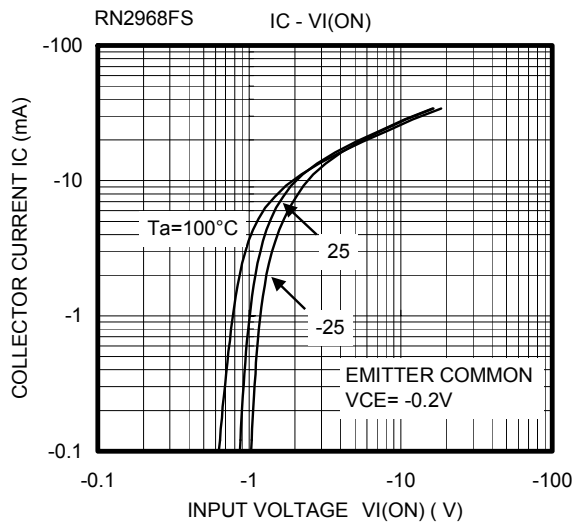
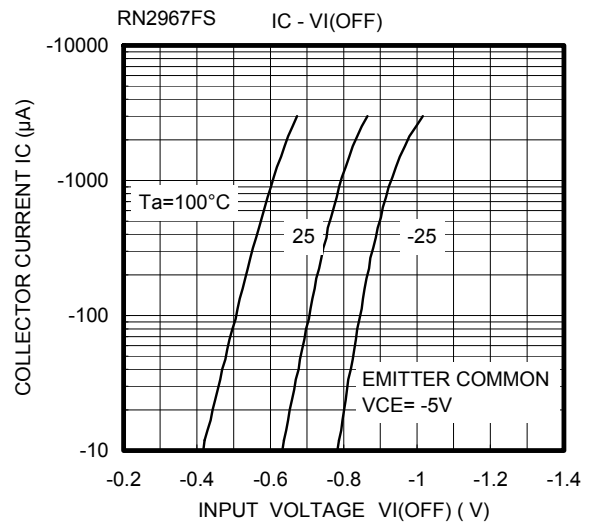
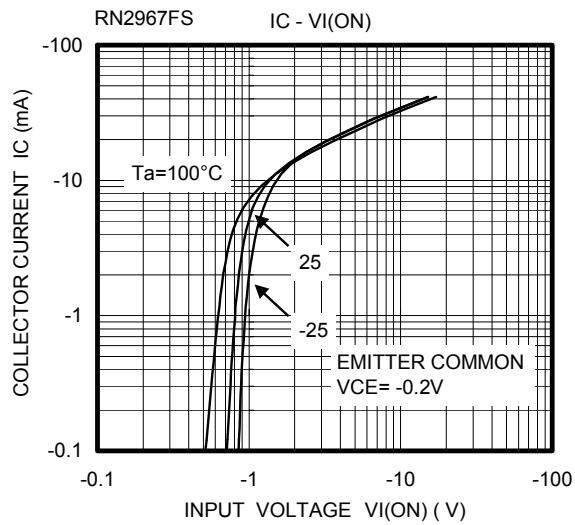
Equivalent Circuit (top view)



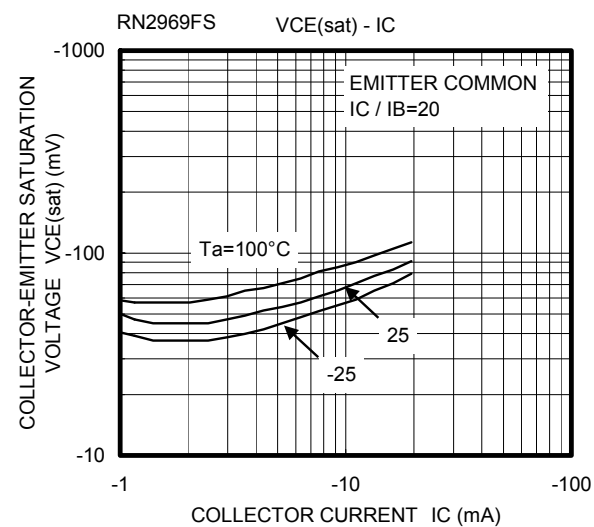
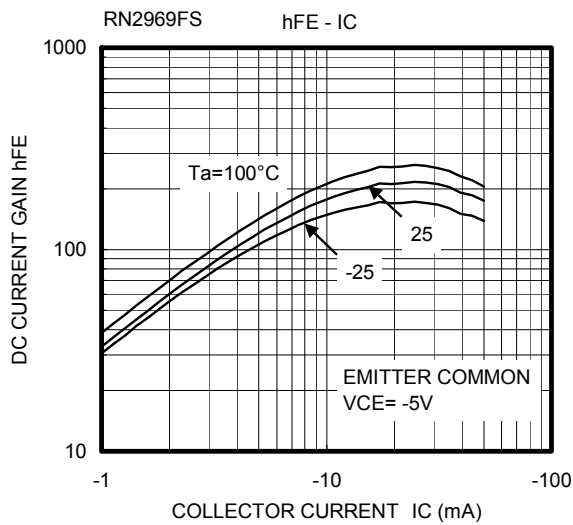
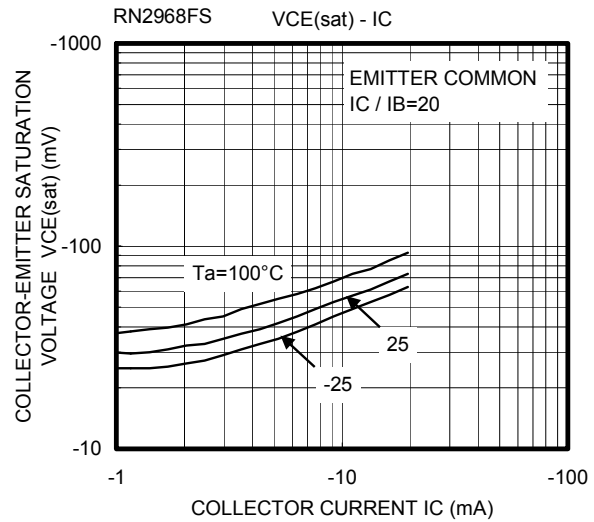
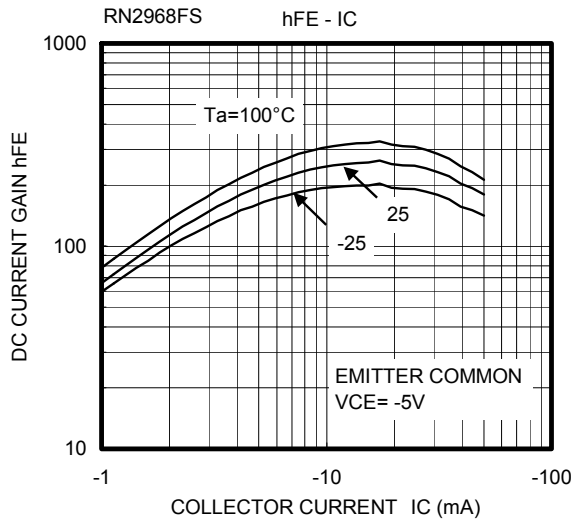
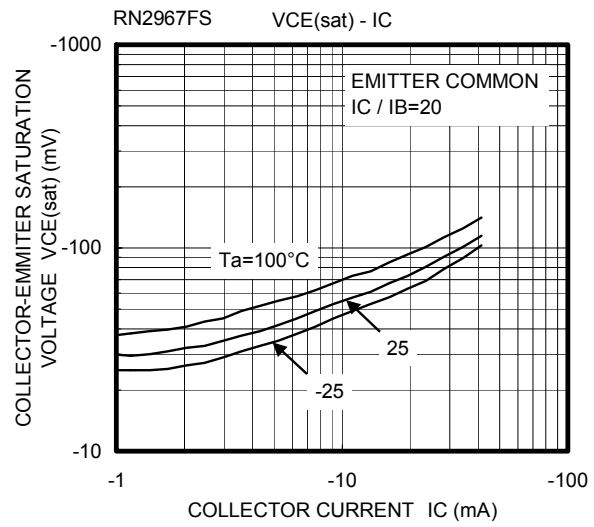
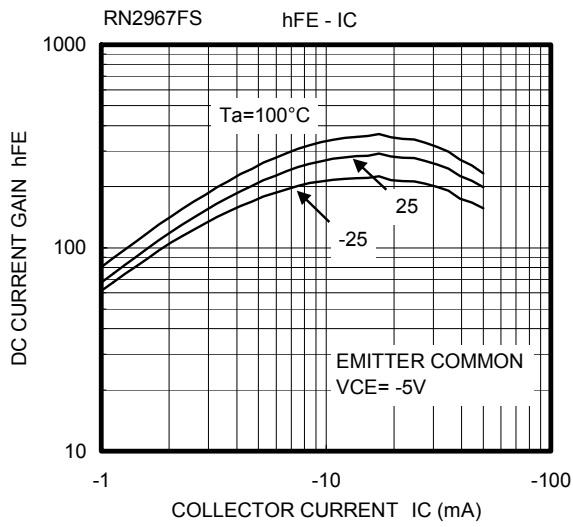
Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN2967FS~2969FS	I_{CBO}	$V_{CB} = -20\text{ V}, I_E = 0$	—	—	-100	nA
		I_{CEO}	$V_{CE} = -20\text{ V}, I_B = 0$	—	—	-500	
Emitter cut-off current	RN2967FS	I_{EBO}	$V_{EB} = -6\text{ V}, I_C = 0$	-0.088	—	-0.131	mA
	RN2968FS		$V_{EB} = -7\text{ V}, I_C = 0$	-0.085	—	-0.126	
	RN2969FS		$V_{EB} = -15\text{ V}, I_C = 0$	0.182	—	-0.271	
DC current gain	RN2967FS	h_{FE}	$V_{CE} = -5\text{ V},$ $I_C = -10\text{ mA}$	120	—	—	
	RN2968FS			120	—	—	
	RN2969FS			100	—	—	
Collector-emitter saturation voltage	RN2967FS~2969FS	$V_{CE(sat)}$	$I_C = -5\text{ mA},$ $I_B = -0.25\text{ mA}$	—	—	-0.15	V
Input voltage (ON)	RN2967FS	$V_{I(ON)}$	$V_{CE} = -0.2\text{ V},$ $I_C = -5\text{ mA}$	-0.7	—	-1.5	V
	RN2968FS			-0.8	—	-2.2	
	RN2969FS			-1.6	—	-5.0	
Input voltage (OFF)	RN2967FS	$V_{I(OFF)}$	$V_{CE} = -5\text{ V},$ $I_C = -0.1\text{ mA},$	-0.5	—	-1.0	V
	RN2968FS			-0.6	—	-1.1	
	RN2969FS			-1.3	—	-2.6	
Collector output capacitance	RN2967FS~2969FS	C_{ob}	$V_{CB} = -10\text{ V}, I_E = 0,$ $f = 1\text{ MHz}$	—	1.2	—	pF
Input resistor	RN2967FS	R1	—	8	10	12	kΩ
	RN2968FS			17.6	22	26.4	
	RN2969FS			37.6	47	56.4	
Resistor ratio	RN2967FS	R1/R2	—	0.17	0.213	0.255	
	RN2968FS			0.374	0.468	0.562	
	RN2969FS			1.71	2.14	2.56	

(Q1,Q2 common)



(Q1,Q2 common)



Type Name	Marking
RN2967FS	
RN2968FS	
RN2969FS	

HANDLING PRECAUTION

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

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